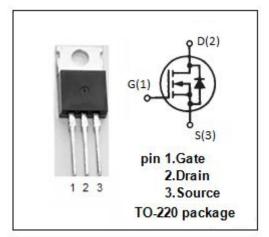


isc N-Channel MOSFET Transistor

PSMN1R9-40PL

FEATURES

- Drain Current –I_D= 150A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 40V(Min)
- · Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 1.7 \text{m} \Omega \text{ (Max)}$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

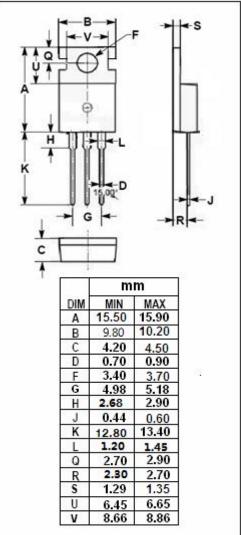
 Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|-------|--------------|
| V _{DSS} | Drain-Source Voltage | 40 | V |
| V _G s | Gate-Source Voltage-Continuous ±2 | | V |
| I _D | Drain Current-Continuous | 150 | А |
| I _{DM} | Drain Current-Single Pluse | 1332 | А |
| P _D | Total Dissipation @T _C =25℃ | | W |
| TJ | Max. Operating Junction Temperature -55~175 | | $^{\circ}$ |
| T _{stg} | Storage Temperature -55~175 | | $^{\circ}$ C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|------|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 0.43 | °C/W |



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|----------------------|---------------------------------|--|-----|------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 0.25mA | 40 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V_{DS} = V_{GS} ; I_D = 1mA | 1.4 | 2.1 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 25A | | 1.7 | mΩ |
| lgss | Gate-Body Leakage Current | V _{GS} = ±16V;V _{DS} = 0 | | ±100 | nA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 40V; V _{GS} = 0 | | 1.0 | μА |
| V _{SD} | Forward On-Voltage | I _S = 25A; V _{GS} = 0 | | 1.2 | V |

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